# NSN 5962-01-379-4679

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-01-379-4679

# Maximum Power Dissipation Rating:

0.6 watts

#### **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

# Storage Tempurature Range:

-65.0/+150.0 degrees celsius

#### **End Application:**

Wgu-2c/b guid e/i fscm 96214

#### **Features Provided:**

Bipolar and programmed and tested to mil-std-883

#### Inclosure Configuration:

Dual-in-line

Input Circuit Pattern:

16 input

#### **Case Outline Source And Designator:**

D-8 mil-m-38510

#### **Terminal Surface Treatment:**

Solder

# **Product Name:**

Programmable array logic, altered

## Voltage Rating And Type Per Characteristic:

-0.5 volts absolute input and 5.5 volts absolute input

## Memory Device Type:

Pal

## Hybrid Technology Type:

Monolithic

## **Test Data Document:**

81349-mil--38510 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

## Terminal Type And Quantity:

20 printed circuit

## **Specification Data:**

81349--38510/50605bra government specification and 67268-5962-8515505ra government standard

#### **Departure From Cited Designator:**

Programmed per: 704as11591-102

Shelf Life:

N/a

#### Unit Of Measure:

--

# Demilitarization:

Yes - demil/mli

# Fiig:

A458a0